

Sub	stitute for form 1449A/B/PT	0		Complete If Known					
		•		Application Number	10/672,961 (Conf. No. 9439)				
11	IFORMATION	DI	SCLOSURE	Filing Date	September 26, 2003				
S	TATEMENT E	3Y /	APPLICANT	First Named Inventor	Glenn J. Leedy				
_				Art Unit	2822				
	(Use as many she	ets as	necessary)	Examiner Name	Monica Lewis				
Sheet	1	of	2	Attorney Docket Number	ELM-2 Cont. 4				

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Examiner Initials*	Cite No.	Document Number Number-Kind Code ² (if known)	Publication Date Name of Patentee or Applicant of Cited Document		Pages, Columns, Lines, Where Relevant Passages or Relevan Figures Appear		
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Examiner Signature	Date Considered	1100

PTO/SB/08a/b (08-03)
Approved for use through 07/31/2008. OMB 0851-0031
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00.	3.11.01.01.11.11.11.11.11.11.11.11.11.11.			Application Number	10/672,961 (Conf. No. 9439)			
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Sheet	2	of	2	Attorney Docket Number	ELM-2 Cont. 4			

	:	NON PATENT LITERATURE DOCUMENTS					
Examiner Initials	er Cite No. 1 Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), pul and/or country where published.						
-		Wolf, Stanley and Richard N. Tauber; Silicon Processing For the VLSI Era. Volume 1: Process Technology; Sunset Beach, CA: Lattice Press, 1986, pages 191-194					
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. *Applicant's unique citation designation number (optional). *See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. *Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). *For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. *Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.18 if possible. *Applicant is to place a check mark here if English language Translation is attached.

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Examiner Signature	11	1	7		Date Considered	1	11	0	(Y)	